

Exam. Code : 103205

Subject Code : 8822

B.A./B.Sc. 5th Semester (Old Syll. 2018)

PHYSICS

Paper—B (Electronics)

Time Allowed—3 Hours] [Maximum Marks—35

Note :— Section A is compulsory. Attempt **one** question from Sections B, C, D and E. All questions carry equal marks.

SECTION—A

1. (a) What is the need of doping a pure semiconductor ?
- (b) What are the disadvantages of a half wave rectifier ?
- (c) Why is *CE* configuration most widely used in amplifiers ?
- (d) Why *FET* is called a unipolar device ?
- (e) What is the effect of negative feedback on voltage gain of amplifier ?
- (f) Why at least three *RC* sections are used in Phase shift oscillator ?
- (g) What is the effect of forward and reverse bias on depletion region ?

SECTION—B

2. Explain the working of forward biased and reverse biased $p-n$ junction diode using the energy band diagram.

OR

3. Explain the working of a bridge rectifier. What is its ripple factor, efficiency and peak inverse voltage ?

SECTION—C

4. Describe the input and output static characteristics of a CE npn transistor. Explain the active, saturation and cut off regions. What is Early Effect ?

OR

5. What are the different types of $MOSFET$'s ? Explain with a neat sketch the working of a p -channel enhancement type $MOSFET$.

SECTION—D

6. (a) Explain how negative feedback decreases the non linear distortion of an amplifier.
(b) Show that negative feedback improves the gain stability of an amplifier.

OR

7. Draw the low frequency h parameters equivalent circuit of a CE transistor amplifier. Derive expression for input resistance, output resistance, current gain, voltage gain and power gain.

SECTION—E

8. Describe the operation from the circuit diagram of a tuned collector oscillator. Derive the condition for sustained oscillations.

OR

9. Determine the frequency of oscillations and condition for sustained oscillations in Hartley oscillator.